TOSHIBA Photocoupler GaAℓAs Ired & Photo IC

6N138, 6N139

Current Loop Driver.

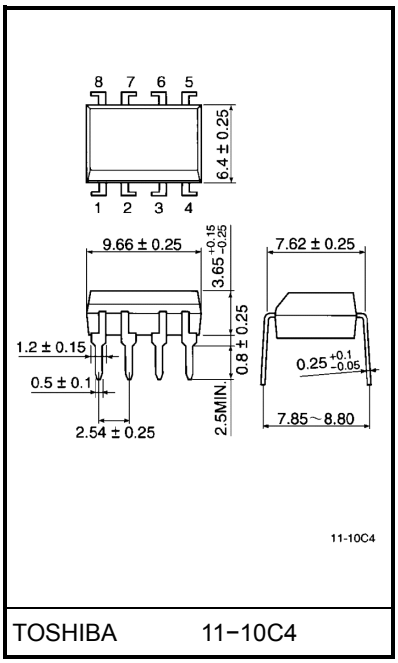
Low Input Current Line Receiver.

CMOS Logic Interface.

The TOSHIBA 6N138 and 6N139 consists of a GaAℓAs infrared
emitting diode coupled with a split-Darlington output configuration.
A high speed GaAℓAs Ired manufactured with an unique LPE junction, has the virtue of fast rise and fall time at low drive current.

- Isolation voltage: 2500Vrms (min.)
- Current transfer ratio
  : 6N138 − 300% (min.) (I_F=1.6mA)
  : 6N139 − 400% (min.) (I_F=0.5mA)
- Switching time: 6N138 − t_{PHL}=10μs (max.)
  − t_{PLH}=35μs (max.)
  6N139 − t_{PHL}=1μs (max.)
  − t_{PLH}=7μs (max.)
- UL recognized: UL1577, file no. E67349

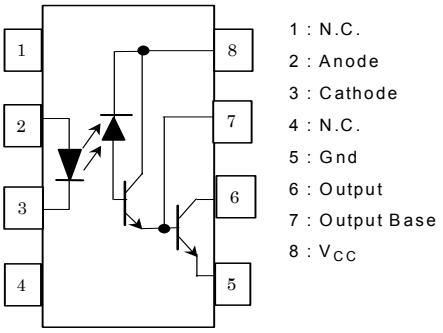
Unit in mm



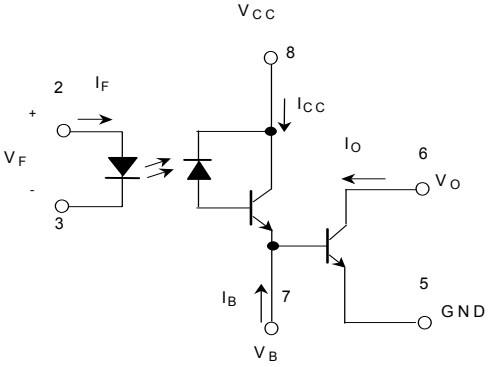
TOSHIBA 11−10C4

Weight: 0.54 g

Pin Configuration (top view)



Schematic



Maximum Ratings (*) (Ta = 0°C to + 70°C)

	Characteristic		Symbol	Rating	Unit
LED	Forward current	(Note 1)	I_F	20	mA
	Pulse forward current		I_{FP} (*1)	40	mA
	Total pulse forward current		I_{FP} (*2)	1	A
	Reverse voltage		V_R	5	V
	Diode power dissipation	(Note 2)	P_D	35	mW
Detector	Output current	(Note 3)	I_O	60	mA
	Emitter−base reverse voltage		V_{EB}	0.5	V
	Supply voltage		V_{CC} (*3)	−0.5 to 18	V
	Output voltage		V_O (*3)	−0.5 to 18	V
	Output power dissipation	(Note 4)	P_O	100	mW
Operating temperature range			T_{opr}	0 to 70	°C
Storage temperature range			T_{stg}	−55 to 125	°C
Lead solder temperature (10s) (*4)			T_{sol}	260	°C
Isolation voltage (1min., R.H.≤ 60%)			BV_S (**)	2500	V_{rms}
				3540	V_{dc}

(*) JEDEC registered data
(**) Not registered JEDEC
(*1) 50% duty cycle, 1ms pulse width
(*2) Pulse width 1μs, 300pps
(*3) 6N138··· −0.5 to 7V
(*4) 1.6mm below seating plane

Electrical Characteristics
Over Recommended Temperature (Ta = 0°C to 70°C, unless otherwise noted)

Characteristic		Symbol	Test Condition	Min.	(*5)Typ.	Max.	Unit
Current transfer ratio (Note 5, 6)	6N139	CTR(*)	I_F=0.5mA, V_O=0.4V, V_{CC}=4.5V	400	800	—	%
			I_F=1.6mA, V_O=0.4V, V_{CC}=4.5V	500	900	—	
	6N138			300	600	—	
Logic low output voltage (Note 6)	6N139	V_{OL}	I_F=1.6mA, I_O=6.4mA, V_{CC}=4.5V	—	0.1	0.4	V
			I_F=5mA, I_O=15mA, V_{CC}=4.5V	—	0.1	0.4	
			I_F=12mA, I_O=24mA, V_{CC}=4.5V	—	0.2	0.4	
	6N138		I_F=1.6mA, I_O=4.8mA, V_{CC}=4.5V	—	0.1	0.4	
Logic high output current (Note 6)	6N139	I_{OH}(*)	I_F=0mA, V_O=V_{CC}=18V	—	0.05	100	μA
	6N138		I_F=0mA, V_O=V_{CC}=7V	—	0.05	250	
Logic low supply current (Note 6)		I_{CCL}	I_F=1.6mA, V_O=Open, V_{CC}=5V	—	0.2	—	mA
Logic high supply current (Note 6)		I_{CCH}	I_F=0mA, V_O=Open, V_{CC}=5V	—	10	—	nA
Input forward voltage		V_F(*)	I_F=1.6mA, Ta=25°C	—	1.65	1.7	V
Input reverse breakdown voltage		BV_R(*)	I_R=10μA, Ta=25°C	5	—	—	V
Temperature coefficient of forward voltage		$\Delta V_F / \Delta Ta$	I_F=1.6mA	—	−1.9	—	mV / °C
Input capacitance		C_{IN}	f=1MHz, V_F=0	—	60	—	pF
Resistance (input−output)		R_{I-O}	V_{I-O}=500V (Note 7), R.H.≤ 60%	—	10^{12}	—	Ω
Capacitance (input−output)		C_{I-O}	f=1MHz (Note 7)	—	0.6	—	pF

(**) JEDEC registered data.

(*5) All typicals at Ta=25°C and V_{CC}=5V, unless otherwise noted.

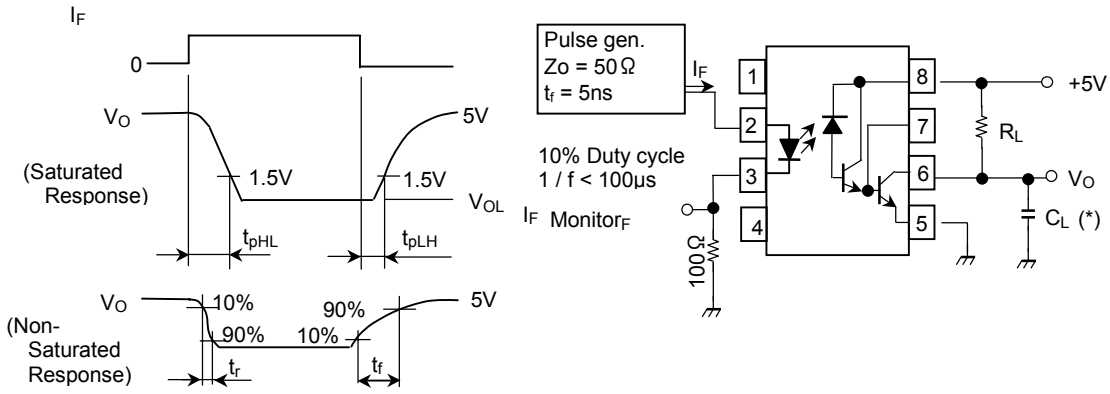
Switching Specifications (Ta=25°C, V_{CC}=5V, unless otherwise specified)

Characteristic		Symbol	Test Circuit	Test Condition	Min.	Typ.	Max.	Unit
Propagation delay time to logic low at output (Note 6, 8)	6N139	t_{pHL}(*)	1	I_F=0.5mA, R_L=4.7kΩ	—	5	25	μs
				I_F=12mA, R_L=270Ω	—	0.2	1	
	6N138			I_F=1.6mA, R_L=2.2kΩ	—	1	10	
Propagation delay time to logic high at output (Note 6, 8)	6N139	t_{pLH}(*)	1	I_F=0.5mA, R_L=4.7kΩ	—	5	60	μs
				I_F=12mA, R_L=270Ω	—	1	7	
	6N138			I_F=1.6mA, R_L=2.2kΩ	—	4	35	
Common mode transient immunity at logic high level output (Note 9)		CM_H	2	I_F=0mA, R_L=2.2kΩ V_{CM}=400V_{p-p}	—	500	—	V / μs
Common mode transient immunity at logic low level output (Note 9)		CM_L	2	I_F=1.6mA R_L=2.2kΩ V_{CM}=400V_{p-p}	—	−500	—	V / μs

(*)JEDEC registered data.

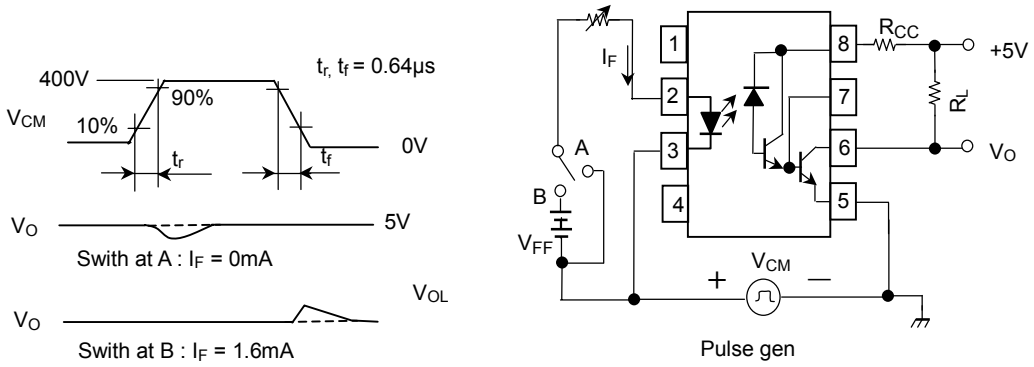
(Note 1): Derate linearly above 50°C free−air temperature at a rate of 0.4mA / °C
(Note 2): Derate linearly above 50°C free−air temperature at a rate of 0.7mW / °C
(Note 3): Derate linearly above 25°C free−air temperature at a rate of 0.7mA / °C
(Note 4): Derate linearly above 25°C free−air temperature at a rate of 2.0mW / °C
(Note 5): DC CURRENT TRANSFER RATIO is defined as the ratio of output collector current, I_O, to the forward LED input current, I_F, times 100%.
(Note 6): Pin 7 open.
(Note 7): Device considered a two−terminal device: Pins 1, 2, 3, and 4 shorted together and Pins 5, 6, 7 and 8 shorted together.
(Note 8): Use of a resistor between pin 5 and 7 will decrease gain and delay time.
(Note 9): Common mode transient immunity in logic high level is the maximum tolerable (positive) dv_{CM} / dt on the leading edge of the common mode pulse, V_{CM}, to assure that the output will remain in a logic high state (i.e., V_O > 2.0V).
Common mode transient immunity in Logic Low level is the maximum tolerable (negative) dv_{CM} / dt on the trailing edge of the common mode pulse signal, V_{CM}, to assure that the output will remain in a logic low state (i.e., V_O < 0.8V).

Test Circuit 1.



(*)C_L is approximately 15pF which includes probe and stray wiring capacitance.

Test Circuit 2.



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